

View Online at <https://aerobasegroup.com/nsn/5961-01-521-1582>

Inclosure Material:

Metal all transistor

Overall Height:

0.350 inches all transistor

Overall Diameter:

0.875 inches all transistor

Function For Which Designed:

Amplifier

Mounting Facility Quantity:

2 all transistor

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

T0-3 all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Unthreaded hole all transistor

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

180.0 collector to base voltage/static/emitter open all transistor

Current Rating Per Characteristic:

16.00 amperes zero-gate-voltage source current blank all transistor

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector all transistor

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius junction all transistor

Terminal Type And Quantity:

2 pin all transistor

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0